

Features

- Low On-resistance and Low Conduction Loss
- Super Junction technology for High Voltage Application
- Soft Switching with Fast Reverse Recovery Diode
- Ultra Low Gate Charge Cause Lower Driving Requirement
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green "Device(Note 1)
- Lead Free Finish/RoHS Compliant(Note2). "P" Suffix Designates RoHS Compliant. See Ordering Information

Maximum Ratings

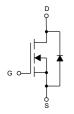
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 40°C/W Junction to Ambient (Note 3)
- Thermal Resistance: 0.4°C/W Junction to Case

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	600	V	
Gate-Source Volltage		V_{GS}	±30	V	
Continuous Drain Current	T _C =25°C	- I _D	41	А	
	T _C =100°C	- 'D	26		
Pulsed Drain Current (Note 4)		I _{DM}	164	Α	
Total Power Dissipation (Note 5)		P _D	312.5	W	
Single Pulsed Avalanche Energy ^(Note 6)		E _{AS}	132	mJ	

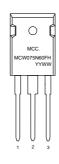
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. High temperature solder exemption applied, see EU directive annex 7a.
- 3. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 4. Repetitive rating; pulse width limited by max. junction temperature.
- 5. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 6. T_J=25°C, V_{DD}=50V, V_{GS}=10V, I_{AS}=23A.

Internal Structure and Marking Code

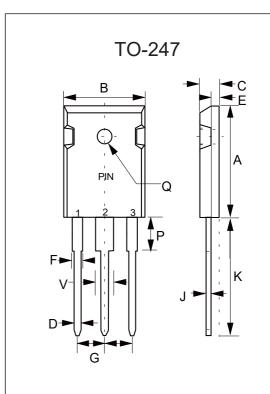


- 1. Gate
- 2. Drain



Device Code: MCW075N60FH Date Code: YYWW (Year & Week)

N-CHANNEL Super-Junction Power MOSFET



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	INOTE
Α	0.787	0.866	20.00	22.00	
В	0.598	0.638	15.20	16.20	
С	0.185	0.208	4.70	5.30	
D	0.035	0.059	0.90	1.50	
E	0.059	0.094	1.50	2.40	
F	0.067	0.091	1.70	2.30	
J	0.019	0.031	0.48	0.80	
K	0.748	0.833	19.00	21.15	
Р	0.122	0.189	3.10	4.80	
Q	0.118	0.150	3.00	3.80	Ф
V	0.106	0.134	2.70	3.40	
G	0.197	0.224	5.00	5.70	

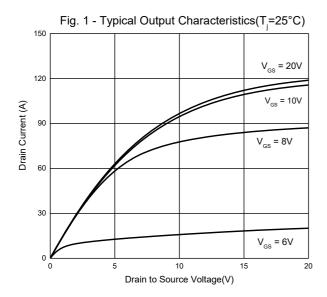


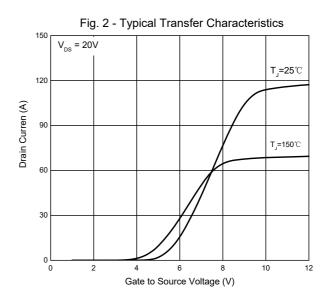
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

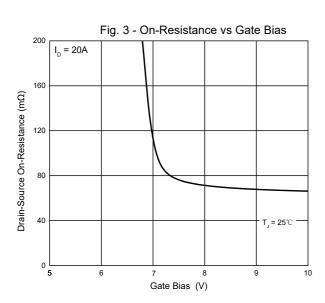
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =1mA	600			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±30V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V			10	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =2.8mA	3	4	5	V	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		65	75	mΩ	
Gate Resistance	R_g	f=1MHz, open drain		1		Ω	
Diode Characteristics							
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A		0.9	1.2	V	
Reverse Recovery Time	t _{rr}			115		ns	
Reverse Recovery Charge	Q _{rr}	V _R =400V, I _F =20A dI _F /dt=100A/µs		723		nC	
Peak Reverse Recovery Current	I _{rrm}			11		А	
Dynamic Characteristics							
Input Capacitance	C _{iss}			3202			
Output Capacitance	C _{oss}	V _{DS} =100V, V _{GS} =0V, f=1MHz		135		pF	
Reverse Transfer Capacitance	C _{rss}			5.5		1	
Total Gate Charge	Q _g			81			
Gate-Source Charge	Q_{gs}	V _{DS} =400V, V _{GS} =10V, I _D =20A		21		nC	
Gate-Drain Charge	Q_{gd}			41			
Turn-On Delay Time	t _{d(on)}			113			
Turn-On Rise Time	t _r	V _{DD} =400V, V _{GS} =10V		34		ns	
Turn-Off Delay Time	t _{d(off)}	R_{G} =5.6Ω, I_{D} =20A		57			
Turn-Off Fall Time	t _f			15			

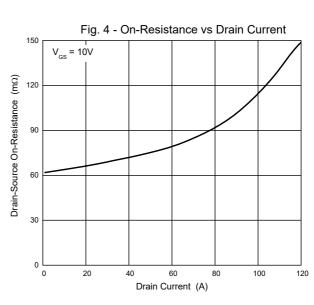


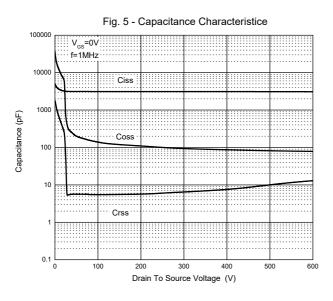
Curve Characteristics

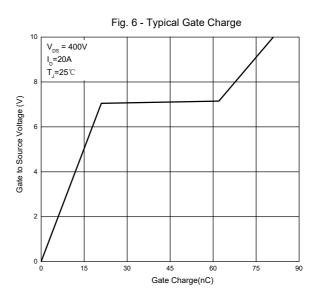






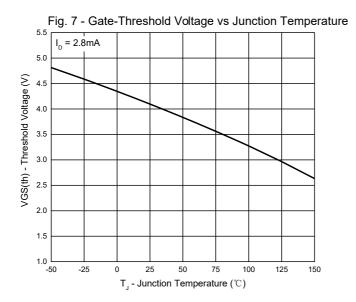


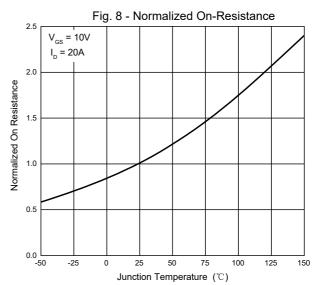


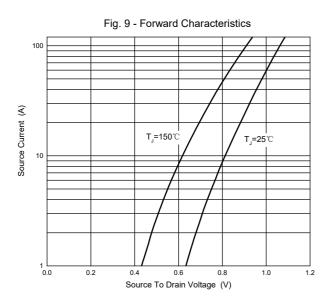


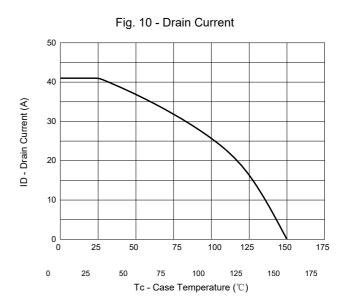


Curve Characteristics









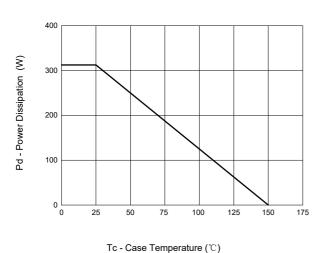
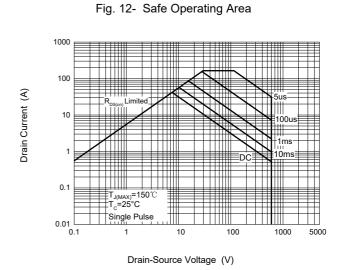


Fig. 11 - Power Dissipation





Zth(J-C) Normalized Transient Thermal Resistance

Curve Characteristics

10

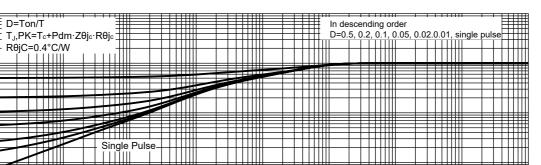
0.1

0.01

1E-3 L 1E-6 1E-5

1E-4

1E-3



0.1

1

10

100

0.01

Fig.13 - Normalized Transient Thermal Impedance

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Ordering Information

Device	Packing	
Part Number-BP	Tube:30pcs/Tube, 360pcs/Box,1.8K/Ctn;	

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